

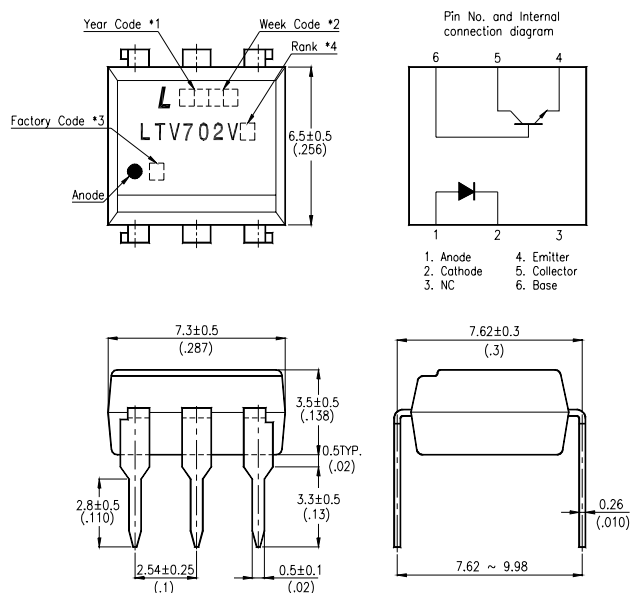
FEATURES

- * Directly connectable to TTL
- * High collector-emitter voltage
($V_{CEO} = 70V$)
- * High input-output isolation voltage
($V_{iso} = 5,000V_{rms}$)
- * Response time
(t_r : TYP. $2\mu s$ at $V_{CC} = 5V$, $I_F = 10mA$, $R_L = 75\Omega$)
- * Current transfer ratio
(CTR : MIN. 40% at $I_F = 10mA$, $V_{CE} = 5V$)
- * Dual-in-line package :
LTV-702V
- * Wide lead spacing package :
LTV-702VM
- * Surface mounting package :
LTV-702VS
- * Tape and reel packaging :
LTV-702VS-TA1
- * UL approved (No. E113898)
- * TUV approved (No. R9653630)
- * CSA approved (No. CA91533-1)
- * FIMKO approved (No. 193422-01)
- * NEMKO approved (No. P96103013)
- * DEMKO approved (No. 303968)
- * SEMKO approved (No. 9646047 / 01-30)
- * VDE approved (No. 094722)

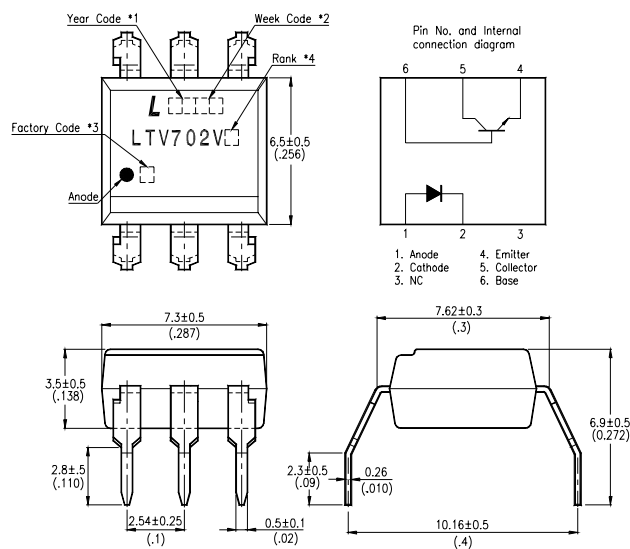
Property of LITE-ON Only

OUTLINE DIMENSIONS

LTV-702V :



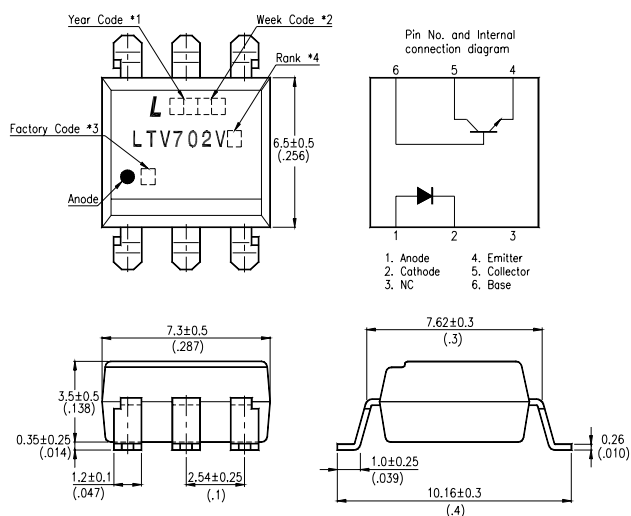
LTV-702VM :



- *1. Year date code.
- *2. 2-digit work week.
- *3. Factory identification mark shall be marked (Z : Taiwan, Y : Thailand, X : China).
- *4. Rank shall be or shall not be marked.

OUTLINE DIMENSIONS

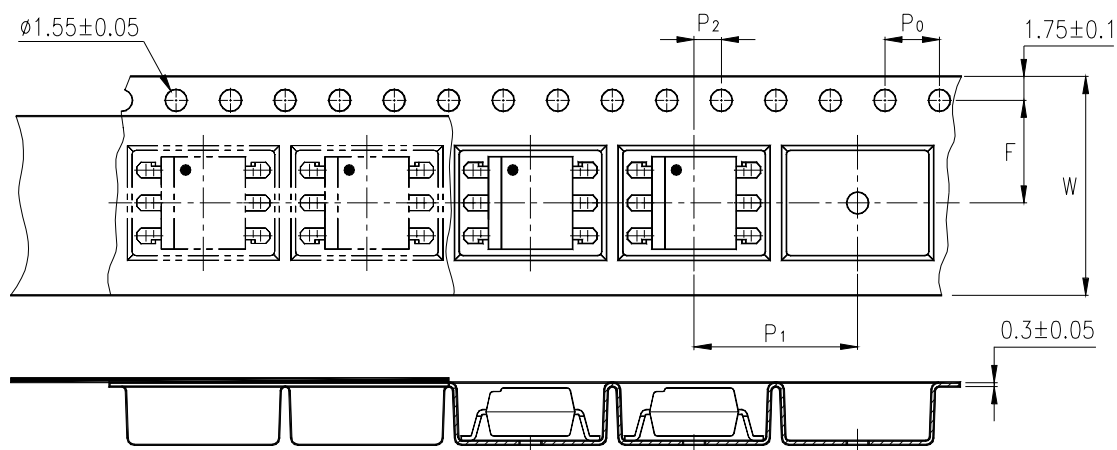
LTV-702VS :



- *1. Year date code.
- *2. 2-digit work week.
- *3. Factory identification mark shall be marked (Z : Taiwan, Y : Thailand, X : China).
- *4. Rank shall be or shall not be marked.

TAPING DIMENSIONS

LTV-702VS-TA1 :



Description	Symbol	Dimensions in mm (inches)
Tape wide	W	16 ± 0.3 (.63)
Pitch of sprocket holes	P_0	4 ± 0.1 (.15)
Distance of compartment	F	7.5 ± 0.1 (.295)
Distance of compartment to compartment	P_1	12 ± 0.1 (.472)

ABSOLUTE MAXIMUM RATING

(Ta = 25°C)

PARAMETER		SYMBOL	RATING	UNIT
INPUT	Forward Current	I _F	60	mA
	Reverse Voltage	V _R	6	V
	Power Dissipation	P	105	mW
OUTPUT	Collector - Emitter Voltage	V _{CEO}	70	V
	Emitter - Collector Voltage	V _{ECO}	6	V
	Collector - Base Voltage	V _{CBO}	70	V
	Emitter - Base Voltage	V _{EBO}	6	V
	Collector Current	I _C	50	mA
	Collector Power Dissipation	P _C	160	mW
Total Power Dissipation		P _{tot}	200	mW
*1 Isolation Voltage		V _{iso}	5,000	V _{rms}
Operating Temperature		T _{opr}	-55 ~ +100	°C
Storage Temperature		T _{stg}	-55 ~ +150	°C
*2 Soldering Temperature		T _{sol}	260	°C

*1. AC For 1 Minute, R.H. = 40 ~ 60%

Isolation voltage shall be measured using the following method.

- (1) Short between anode and cathode on the primary side and between collector, emitter and base on the secondary side.
- (2) The isolation voltage tester with zero-cross circuit shall be used.
- (3) The waveform of applied voltage shall be a sine wave.

*2. For 10 Seconds

ELECTRICAL - OPTICAL CHARACTERISTICS

(Ta = 25°C)

PARAMETER		SYMBOL	MIN.	TYP.	MAX.	UNIT	CONDITIONS
INPUT	Forward Voltage	V _F	—	1.4	1.7	V	I _F =60mA
	Reverse Current	I _R	—	—	10	μA	V _R =6V
	Terminal Capacitance	C _t	—	30	250	pF	V=0, f=1KHz
OUTPUT	Collector Dark Current	I _{CEO}	—	—	50	nA	V _{CE} =10V, I _F =0
	Collector-Emitter Breakdown Voltage	BV _{CEO}	70	—	—	V	I _C =0.1mA I _F =0
	Emitter-Collector Breakdown Voltage	BV _{ECO}	6	—	—	V	I _E =10μA I _F =0
	Collector-Base Breakdown Voltage	BV _{CBO}	70	—	—	V	I _C =0.1mA I _F =0
TRANSFER CHARACTERISTICS	Collector Current	I _C	4	—	32	mA	I _F =10mA V _{CE} =5V
	* Current Transfer Ratio	CTR	40	—	320	%	
	Collector-Emitter Saturation Voltage	V _{CE(sat)}	—	0.25	0.4	V	I _F =10mA I _C =2.5mA
	Isolation Resistance	R _{iso}	5×10 ¹⁰	1×10 ¹¹	—	Ω	DC500V 40 ~ 60% R.H.
	Floating Capacitance	C _f	—	0.6	1	pF	V=0, f=1MHz
	Cut-Off Frequency	f _c	—	150	—	kHz	V _{CC} =5V, I _F =10mA R _L =75Ω, -3dB
	Response Time (Rise)	t _r	—	2	7	μs	V _{CC} =5V, I _F =10mA R _L =75Ω
	Response Time (Fall)	t _f	—	2	8	μs	

$$* \text{ CTR} = \frac{I_C}{I_F} \times 100\%$$

RANK TABLE OF CURRENT TRANSFER RATIO CTR

MODEL NO.	RANK MARK	CTR (%)
LTV-702V	A	40 ~ 80
LTV-702V	B	63 ~ 125
LTV-702V	C	100 ~ 200
LTV-702V	D	160 ~ 320
LTV-702V	A or B or C or D or No mark	40 ~ 320

CONDITIONS	$I_F = 10 \text{ mA}$ $V_{CE} = 5 \text{ V}$ $T_a = 25 \text{ }^\circ\text{C}$
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CHARACTERISTICS CURVES

Fig.1 Forward Current vs.
Ambient Temperature

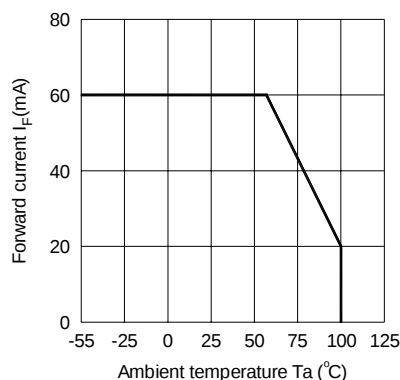


Fig.2 Collector Power Dissipation vs.
Ambient Temperature

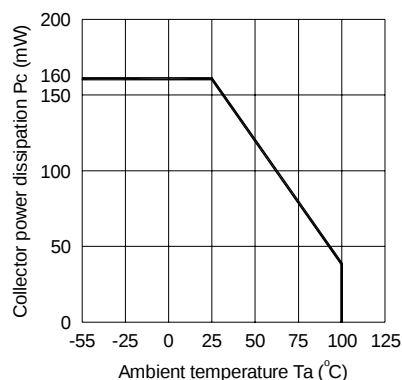


Fig.3 Collector-emitter Saturation
Voltage vs. Forward Current

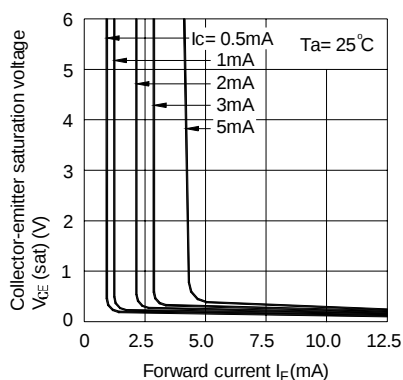


Fig.4 Forward Current vs.
Forward Voltage

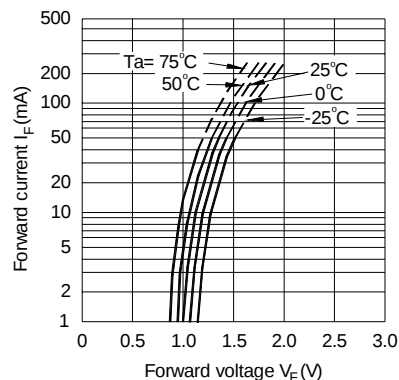


Fig.5 Current Transfer Ratio vs.
Forward Current

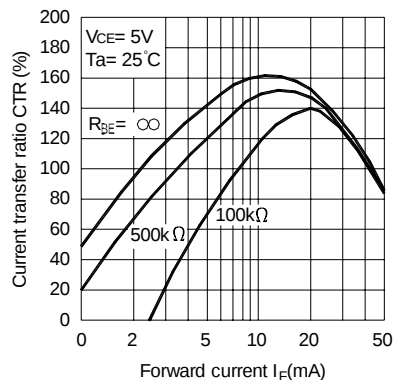
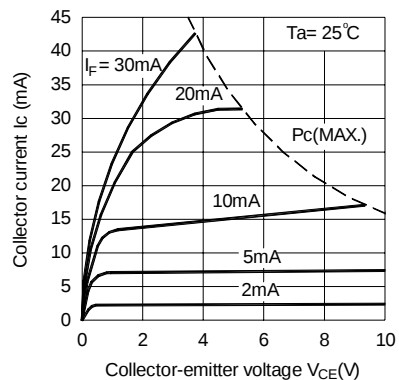


Fig.6 Collector Current vs.
Collector-emitter Voltage



CHARACTERISTICS CURVES

Fig.7 Relative Current Transfer Ratio vs. Ambient Temperature

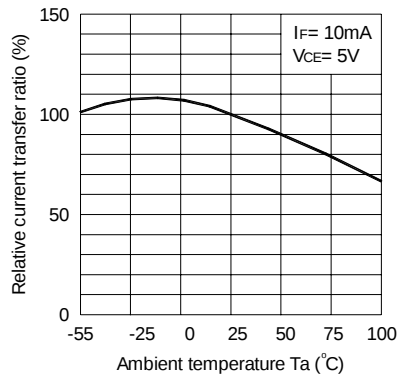


Fig.8 Collector-emitter Saturation Voltage vs. Ambient Temperature

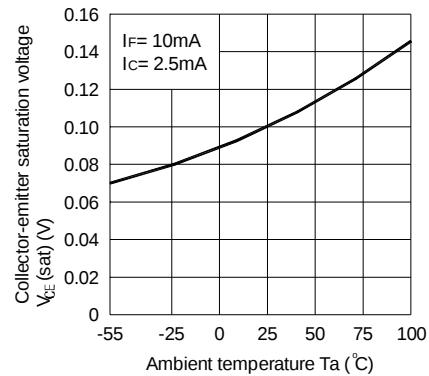


Fig.9 Collector Dark Current vs. Ambient Temperature

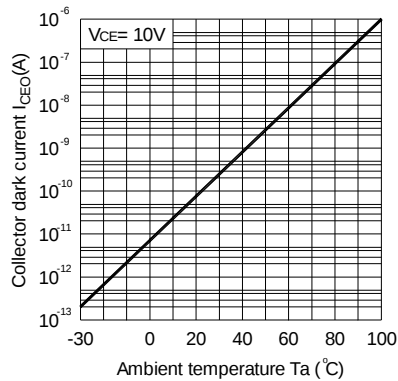


Fig.10 Response Time vs. Load Resistance

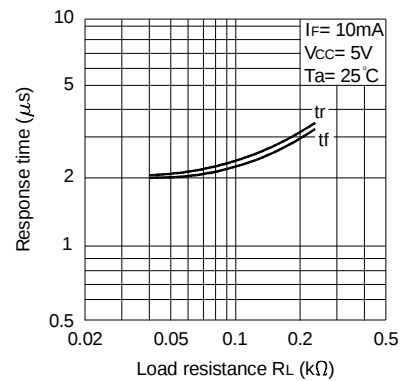
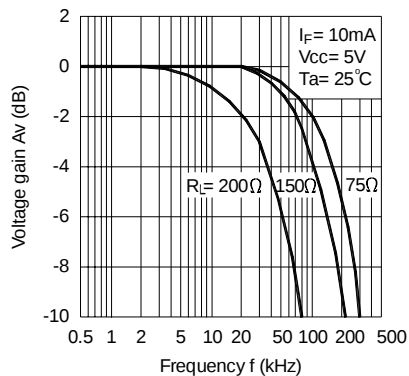
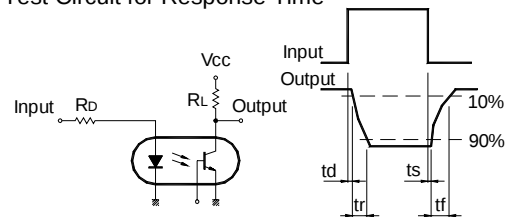


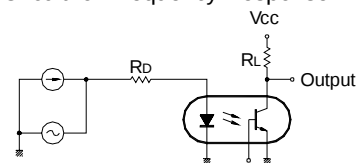
Fig.11 Frequency Response



Test Circuit for Response Time



Test Circuit for Frequency Response



RECOMMENDED FOOT PRINT PATTERNS (MOUNT PAD)

Unit : mm

